Therm al C onductivity of P $r_{1:3}$ $_xLa_{0:7}C e_xC uO_4$ Single C rystals and Signatures of Stripes in an E lectron-D oped C uprate

X.F.Sun, Y.Kurita, T.Suzuki, Seiki Komiya, and Yoichi Ando^y

Central Research Institute of Electric Power Industry, Kom ae, Tokyo 201-8511, Japan.

(D ated: A pril 14, 2024)

It was recently demonstrated that the anisotropic phonon heat transport behavior is a good probe of the stripe form ation in La_{2 x} Sr_xCuO₄ (LSCO) [X.F.Sun et al., Phys. Rev. B 67, 104503 (2003)]. Using this probe, we exam ined an electron-doped cuprate Pr_{1:3 x} La_{0:7}Ce_xCuO₄ (PLCCO) and found that essentially the same features as those in LSCO are observed. Moreover, the in-plane resistivity _{ab} of lightly-doped PLCCO shows m etallic behavior (d_{ab}=dT > 0) in the Neel ordered state with a mobility com parable to that in LSCO. It is discussed that these peculiar properties in com m on with LSCO signify the existence of stripes in electron-doped cuprates.

PACS num bers: 74.25 Fy, 74.72 Jt, 74.62 Dh, 66.70.+ f

High-T_c superconductivity shows up when either holes or electrons are doped to parent M ott-insulating cuprates. The essential features of the phase diagram, such as the Neel ordering in the lightly-doped regime and superconductivity in the moderately-doped regime, are approximately symmetric [1, 2] for hole- and electrondoped sides, with the undoped M ott insulator sitting in the middle, and this leads to a key paradigm in the study of the high-T_c cuprates: the electron-hole sym m etry. However, there are also disparities between the two sides, and understanding the sim ilarities and di erences between the hole- and electron-doped cuprates would be crucial for elucidating the fundam ental nature of these m aterials. O fparticular interest is whether the \stripes" [3] (a sort of quasi-one-dimensional charge/spin density wave) exist in the electron-doped cuprates [4], since such self-organized structures have been observed in the holedoped cuprates [5] and are discussed to be relevant to the occurrence of superconductivity [3].

Most convincing evidence for the stripes in the holedoped cuprates had been obtained by neutron scattering in the form of \incommensurate" superstructure peaks [6, 7, 8, 9]; on the other hand, neutron scattering experim ents on an electron-doped m aterial N d_{2 x} C e_x C uO 4 (NCCO) found only commensurate magnetic peaks to coexist with the superconductivity [10]. Such commensurate peaks would naturally suggest that there is no superstructure in the spin system ; how ever, if the stripes are \in-phase" dom ain boundaries of the spin system that leave strong commensurate peaks (as opposed to antiphase boundaries that give rise to only incom m ensurate peaks), the neutron data on NCCO can be consistent with such stripe structures [11]. Thus, it is still an open question whether the stripes exist in the electron-doped cuprates. Here we show that the transport properties of an electron-doped cuprate dem onstrate peculiar features that are sim ilar to those in the hole-doped cuprates, where such features [12, 13] have been shown to be naturally understood as consequences of the stripe form ation. Therefore, it is most likely that the stripes exist in electron-doped cuprates and that there is an approxim ate electron-hole sym m etry not only for the occurrence of superconductivity but also for the stripe form ation.

Recently, we have demonstrated [13] that the c-axis phonon heat transport is a good probe of the stripe form ation in lightly hole-doped $La_2 \times Sr_xCuO_4$ (LSCO); namely, the spin stripes in this system are well-ordered in the CuO₂ planes but are disordered along the caxis [8], which (perhaps through the strong spin-lattice coupling [14]) causes the c-axis phonons to be strongly scattered. We have also dem onstrated [12] that the in-plane resistivity ab of lightly-doped LSCO crystals shows m etallic behavior (d $_{ab}$ =dT > 0) even in the long-range-ordered Neel state, where the hole mobility is virtually the same as that in optimally-doped samples; such an unusual m etallic behavior can naturally be understood if doped holes form self-organized \rivers" whose distance changes with doping [12, 15]. Taking these features as signatures of stripes, we set out to exam ine the transport properties of (Pr,La)_{2 x} Ce_xCuO₄ (PLCCO) system, for which Fujita et al. reported [16] that high-quality single crystals can be grown by the traveling-solvent oatingzone (TSFZ) technique. We choose the composition of $Pr_{1:3 x} La_{0:7}Ce_{x}CuO_{4}$, which is structurally stable in the lightly Ce-doped region [17].

H igh-quality $Pr_{1:3 \times} La_{0:7}Ce_xCuO_4$ single crystals (x = 0, 0.01, 0.03, 0.05, 0.08, 0.10, and 0.13) are grown by the TSFZ technique in owing oxygen. The crystals are cut into rectangular platelets with a typical size of 2.5 0.5 0.1 mm³, where the c axis is perpendicular or parallel to the platelets within an accuracy of better than 1. The ab-plane and c-axis therm al conductivities (ab and c) are measured by a steady-state technique [13]. Several sam ples are measured for each C e concentration to check for the reproducibility, resulting in the uncertainties in the reported values of less than 10%. Standard ac four-probe method is employed to measure the resistivity [18]. Note that the properties of the electron-doped cuprates are very sensitive to oxygen non-stoichiom etry [19, 20]; reduction annealing is necessary to rem ove ex-

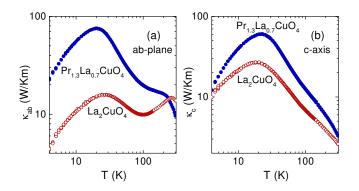


FIG. 1: Thermal conductivity of parent cuprates $Pr_{1:3}La_{0:7}CuO_4$ and La_2CuO_4 (taken from Ref. [13]) along (a) the ab plane and (b) the c axis.

cess (apical) oxygen from oxygenated (as-grown) crystals and to introduce electrons into the CuO₂ planes. For this work, to rem ove su cient apical oxygens while introducing only a sm all am ount of oxygen vacancies in the reduced sam ples, we perform ed therm ogravim etry analyses and settled on the annealing at 850 (875 C for 24 h under A r gas ow [21]. W ith this condition, the di erence in the oxygen content between the oxygenated and reduced sam ples (m easured by the weight change after the A rannealing) is rather sm all (for exam ple, the di erence is 0.1% for the x = 0.05 sam ple).

To begin with, let us discuss the tem perature dependences of ab and c of undoped Pr1:3La0:7CuO4 (PLCO) crystals shown in Fig. 1, where the data for La_2CuO_4 (LCO) [13] are also included for comparison. The LCO crystals exhibit a pronounced phonon peak at low tem perature in both ab and c, while at high tem perature close to the Neel tem perature $T_{\rm N}$ (' 300 K) another peak appears in ab and this has been attributed to the m agnon heat transport [13, 22, 23]. One can see that PLCO shows much higher low-T peak in both ab and c, suggesting an intrinsically better phonon transport in PLCO [24]; also, these data testify the high quality of our crystals. In the $_{ab}$ (T) data, one can further see that the magnon contribution to the heat transport is evident in PLCO, where the larger phonon contribution turns what was a clear peak in LCO into a hum p; note that the position of this hump is consistent with $T_{\rm N}$ (' 260 K in Pr_2CuO_4 [25]). It is fair to note that this is not the rst time a signature of the magnon heat transport in the so-called T⁰-phase is observed, since sim ilar hum p pro le was reported for polycrystalline Pr₂CuO₄ sam ples [26]. How ever, only by using single crystals can one conm that the hump appears only in the ab plane, which is essential for attributing this hum p to the m agnons in two-dimensional (2D) spin systems.

Figure 2 shows how $_{ab}(T)$ and $_{c}(T)$ of PLCCO change with doping. W ith increasing x, the high-T hum p in $_{ab}$ becomes weaker and alm ost disappears at x =

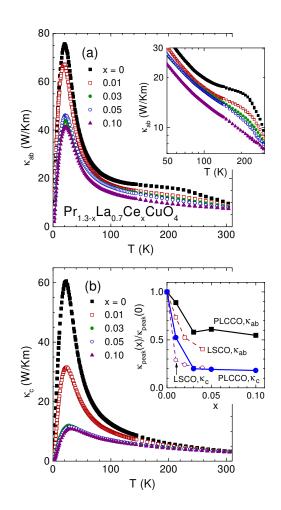


FIG. 2: Therm al conductivity of reduced single crystals of $Pr_{1:3} \times La_{0:7}Ce_xCuO_4$ along (a) the ab plane and (b) the c axis. Insets: (a) _{ab}(T) data near the high-T hum p in a log-log plot; (b) Doping dependences of the peak values of _{ab} and _c, norm alized by the values at x = 0, for PLCCO and LSCO (data for LSCO are taken from Ref. [13]).

0.05 [which can be better seen in the inset to Fig. 2(a)], even though the N eel tem perature shows just a weak x-dependence up to x = 0.08 in PLCCO [16]. This behavior is som ewhat sim ilar to that in LSCO, where the m agnon peak is completely suppressed with only 1%-Sr-doping, for which T_N is still as high as 240 K [13].

The main nding in Fig. 2 is that the low-T phonon peak show svery anisotropic evolution upon electron doping; namely, the low-T peak of $_{\rm C}$ is dram atically suppressed with slight C e doping, while the doping e ect on $_{\rm ab}$ is much more modest. The inset to Fig. 2(b) shows a plot of the x-dependence of the peak height relative to that of x = 0; here, sim ilar data for LSCO [13] are also show n. O ne can see that the drastic suppression of the c-axis phonon peak upon slight carrier doping is com - m on to LSCO and PLCCO. Note that the contribution of electronic heat transport is negligibly small at low tem - peratures in these insulating crystals [13], so the doping dependence in the low-T heat transport is solely due to

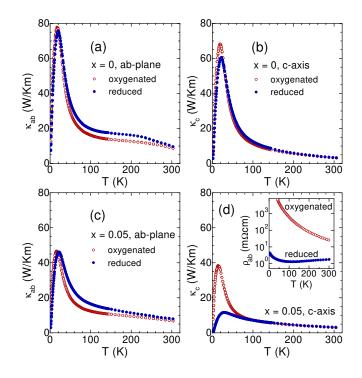


FIG. 3: Comparison of the thermal conductivity of oxygenated and reduced Pr_{1:3} $_x$ La_{0:7}Ce_xCuO₄ single crystals for (a,b) x = 0 and (c,d) x = 0.05. Inset to panel (d) shows $_{ab}$ (T) data of oxygenated and reduced sam ples for x = 0.05.

som e doping-induced scattering of phonons.

There are several possibilities for this strong dopinginduced phonon scattering, such as the usual impurityphonon scattering, electron-phonon scattering, and bcal structural distortions induced by ion substitutions. For PLCCO, thanks to the peculiar role of oxygen nonstoichiom etry [16, 19], a good way to clarify the phonon scattering m echanism is to compare the behavior of the reduced crystals to that of oxygenated ones, where the charge carrier density in the CuO₂ planes is depleted [20].

Figure 3 shows such comparison for x = 0 and 0.05 crystals, which gives us useful pieces of information: First, it is clear that the rem oval of oxygen little changes the low-T phonon heat transport in undoped crystals [Figs. 3(a) and 3(b)], which implies that the apical oxygen and/or the oxygen vacancies [19] scarcely scatter phonons in both ab-plane and c-axis directions. Second, the peak height in $_{ab}(T)$ for x = 0.05 shows no di erence between the oxygenated and reduced samples Fig. 3 (c)], which suggests that it is the structural distortion due to the Ce doping, rather than the charge carriers, that is mainly responsible for the scattering of the inplane phonons and for the 40% damping of the ab peak compared to x = 0; this structural distortion seem s to scatter phonons isotropically, because the c peak of the oxygenated samples is also reduced by 40% with 0.05 Cedoping [see Figs. 3 (b) and 3 (d)]. Third, the dramatic suppression of the phonon peak in _ with Cedoping is observed only in the reduced sample, which m eans that the strong phonon scattering is de nitely related to the electrons in the CuO₂ planes, even though the electrons have little c-axis dispersion and are not normally expected to scatter c-axis phonons signi cantly. [The inset to Fig. 3 (d) shows a comparison of $_{ab}$ (T) for oxygenated and reduced x = 0.05 samples, which demonstrates how starkly the mobile carrier density changes upon reduction.]

As was discussed in Ref. [13] for the case of LSCO, the lattice distortions induced by the stripes can naturally provide the anisotropic phonon scatterings, when the stripes are well ordered in the planes but are disordered along the caxis (which is actually the case for the spin stripes in LSCO [8]). Given the striking similarities in the suppression of the $_{\rm c}$ peak between LSCO and PLCCO [and also the additional evidence in Fig. 3(d) that the strong phonon dam ping must be related to the doped electrons], it is most reasonable to conclude that the peculiar therm al conductivity behavior in PLCCO is due to the stripes that have been previously undetected, and the data suggest that the stripes are not established for x < 0.03. As is mentioned in the introduction, since the neutron scattering has found com m ensuratem agnetic peaks for NCCO [10], the stripes that are to be form ed in the electron-doped cuprates should be in-phase antiferrom agnetic dom ain boundaries, which do not frustrate the spin periodicity and are benign to the Neel order. We note that existence of the in-phase stripes has been suggested for the weak-ferrom agnetic state of LSCO at x =0.01 under high magnetic eld [18], not to mention the theoretical predictions for them in the literature [27].

It is useful to note that some of the unusual features recently found in NCCO m ight be related to the anom alous therm al conductivity behavior: An optical phonon at 70 meV was found to soften upon slight Ce doping [28], and rather mysterious 2D superlattice structure was observed when NCCO (x = 0.15) was reduced [29]. W hile it is possible that these features are also com ing from some form of spin/charge texture, much remains to be sorted out about the exact roles of Ce doping and reduction in electron-doped cuprates.

In passing, we note that H ess et al. recently argued [30] that the scattering by soft phonons associated with the lattice instability of the low tem perature orthorhom bic (LTO) phase, rather than the scattering by stripes, is the source of the dam ping of the phonon peak in LSCO. However, this picture clearly falls short in explaining the drastic suppression of the $_{\rm c}$ peak in the lightly-doped LSCO, where the LTO transition tem perature does not change much from La₂CuO₄ [2]. Furtherm ore, PLCCO has no LTO instability (this system is tetragonal irrespective of C e doping and tem perature) and yet shows the anom alous dam ping of the phonon peak, which gives another good reason to dism iss the soft phonon scenario.

The tem perature dependences of $_{ab}$ are shown in Fig.

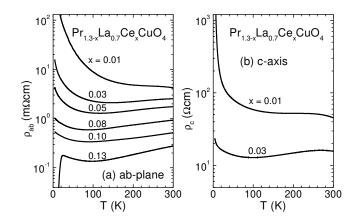


FIG. 4: (a) Tem perature dependences of $_{ab}$ of the reduced single crystals of P $n_{1:3} \times La_{0:7}Ce_xCuO_4$ (x = 0.01 { 0.13) that are A r-annealed at 850{875 C. (b)Tem perature dependences of $_{c}$ of the reduced single crystals at x = 0.01 and 0.03.

4 (a) for $x = 0.01\{0.13\}$. It is intriguing to see that the x =0.01 sample is weakly insulating (d $_{ab}$ =dT < 0) at room tem perature, while the x = 0.03 sample shows a m etallic behavior; this seems to be correlated with the behavior of c, where the anom alous dam ping of the low -T peak saturates above x = 0.03, and suggests that the m etallic behavior in ab is also due to the stripe form ation. A swas discussed for LSCO, observation of a metallic in-plane transport in the long-range N elordered state (T_N should be around 200 K at x = 0.03(0.08 in PLCCO [16]) is anom alous [15], and it is even m ore peculiar that the hole m obility in the Neel state is sim ilar to that at optim um doping [12]. It was proposed that the self-organization of charges into stripes gives a plausible picture to understand this doubly-unusual metallic behavior in the Neel state [12, 15]; apparently, the same discussion is applicable to the lightly electron-doped PLCCO, where the electron mobility is calculated to be around 5 cm²/Vs at 300 K, which is surprisingly sim ilar to that in LSCO and is suggestive of the transport mechanism being the same. Therefore, the ab data give additional support to the conjecture that the stripes are form ed in PLCCO at 0:03. Intriguingly, the tem perature dependence of х the c-axis resistivity (c) also shows a qualitative change between x = 0.01 and 0.03 [Fig. 4(b)].

In summary, two peculiar features in the transport properties, which are considered to signify the existence of stripes in the lightly hole-doped LSCO, are both observed in the lightly electron-doped PLCCO: anom alous damping of the c-axis phonons and the \high m obility" m etallic transport in the Neel ordered state. A natural conclusion of these observations is that the stripes are form ed not only in the hole-doped cuprates but also in the electron-doped cuprates. Thus, there seem s to be an approxim ate electron-hole symmetry for the stripe formation, though the detailed structure of the stripes is likely to be di erent.

W e thank S.A.K ivelson, A.N.Lavrov, and J.Takeya for helpfuldiscussions, and M.Fujita for giving us useful inform ation on the PLCCO crystal grow th.

also at D epartm ent of P hysics, Tokyo U niversity of Science, Shin juku-ku, Tokyo 162-8601, Japan.

- ^y E lectronic address: ando@ criepidenken.or.jp
- [1] H. Takagi, S. Uchida, and Y. Tokura, Phys. Rev. Lett.
 62, 1197 (1989).
- [2] M.A.Kastner et al, Rev.M od. Phys. 70, 897 (1998).
- [3] For a review, see E.W. Carlson, V.J.Emery, S.A.K ivelson, and D.Orgad, cond-m at/0206217.
- [4] A.Sadoriand M.Grilli, Phys.Rev.Lett.84, 5375 (2000).
- [5] Y. Ando et al., Phys. Rev. Lett. 88, 137005 (2002), and references therein.
- [6] J.M. Tranquada et al., Nature 375, 561 (1995).
- [7] K.Yam ada et al, Phys.Rev.B 57, 6165 (1998).
- [8] M. M atsuda et al, Phys. Rev. B 62, 9148 (2000).
- [9] H.A.Mook, P.Dai, and F.Dogan, Phys. Rev. Lett. 88, 097004 (2002).
- [10] K.Yam ada et al, Phys.Rev.Lett. 90, 137004 (2003).
- [11] S.A.Kivelson, private communication.
- [12] Y.Ando et al, Phys.Rev.Lett.87,017001 (2001).
- [13] X.F.Sun et al, Phys.Rev.B 67, 104503 (2003).
- [14] A.N.Lavrov, S.K om iya, and Y.Ando, Nature 418, 385 (2002); cond-m at/0208013.
- [15] Y.Ando, cond-m at/0206332.
- [16] M.Fujita et al, Phys.Rev.B 67, 014514 (2003).
- [17] Y. Ikeda et al., Physica C 378-381, 395 (2002).
- [18] Y.Ando, A.N.Lavrov, and S.K om iya, Phys. Rev. Lett. 90, 247003 (2003).
- [19] A.J.Schultz et al, Phys.Rev.B 53, 5157 (1996).
- [20] W .Jiang et al., Phys. Rev. B 47, 8151 (1993).
- [21] The sm all am ount of oxygen vacancies in our reduced samples introduce some additional electrons, which we estimate to be 2% perCu; annealing at higher temperatures (900{950 C), which stabilizes the superconducting transition for x 0:10 [16], introduces further electron carriers and makes the x value to be not a good measure of the electron doping.
- [22] Y. Nakamura et al., Physica C 185-189, 1409 (1991).
- [23] C.Hess et al, Phys.Rev.Lett. 90, 197002 (2003).
- [24] J.L.Cohn et al, Phys. Rev. B 46, 12053 (1992).
- [25] D.E.Cox et al., Phys. Rev. B 40, 6998 (1989); M.M atsuda et al., Phys. Rev. B 42, 10098 (1990).
- [26] A.V. Sologubenko et al., Physica B 263-264, 788 (1999).
- [27] O.Zachar, Phys. Rev. B 65, 174411 (2002); L.P.P ryadko et al, Phys. Rev. B 60, 7541 (1999).
- [28] H.J.Kang et al, Phys.Rev.B 66, 064506 (2002).
- [29] K.Kurahashiet al, J.Phys.Soc.Jpn.71, 910 (2002).
- [30] C.Hess, B.Buchner, U.Amm erahl, and A.Revcolevschi, cond-m at/0305321.